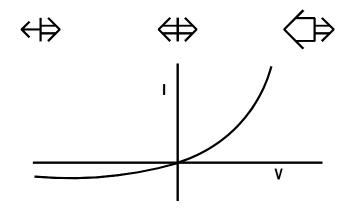
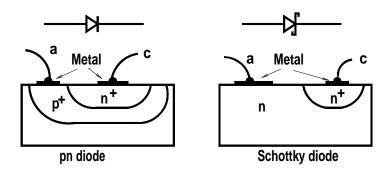
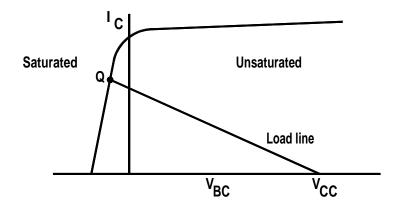
- Metal-semiconductor junction characteristic determined by work functions and semiconductor doping concentrations.
- Schottky diode has a knee voltage of about
 0.2 V and has a very fast response
- A Schottky diode used with an npn transistor prevents minority carrier saturation of the transistor.
- STTL circuits use Schottky transistors and operate at higher speeds than TTL circuits.



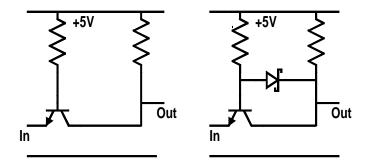
Schottky diode characteristic. Arrow thickness is proportional to majority carrier current in each direction.



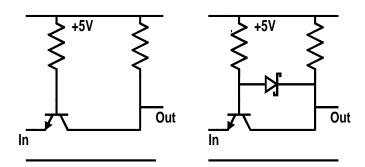
Schottky diode structure.



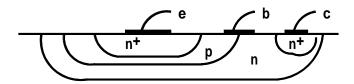
Saturation mechanism in npn transistor.



Schottky diode used to prevent saturation.



Schottky diode used to prevent saturation.



Fabrication structure of Schottky transistor.